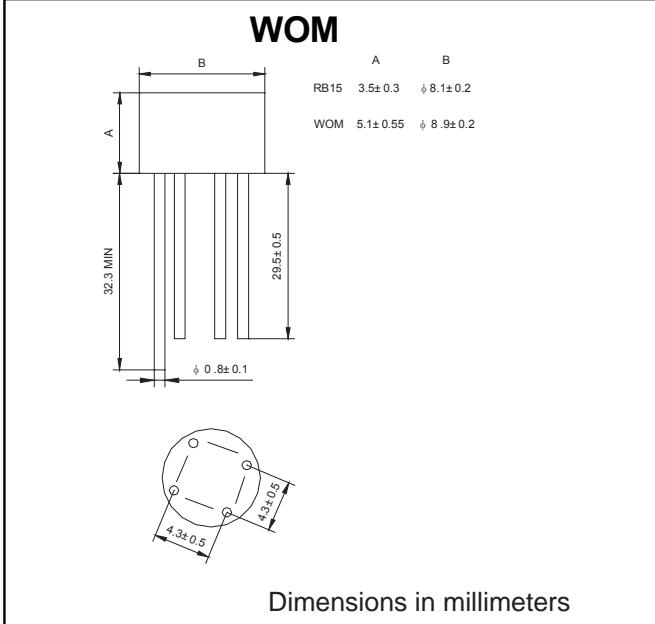


**SILICON BRIDGE RECTIFIER**
**REVERSE VOLTAGE : 50 --- 1000 V CURRENT: 1.5A**
**FEATURES**

- Rating to 1000V PRV
- Surge overload rating to 50 Amperes peak
- Ideal for printed circuit board
- Reliable low cost construction utilizing molded plastic technique results in inexpensive product
- Glass passivated chip junctions

**MECHANICAL DATA**

- Mounting Position: Any


**MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS**

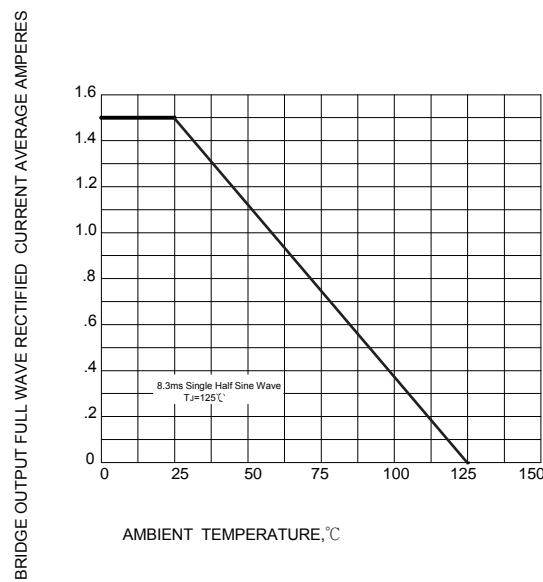
Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

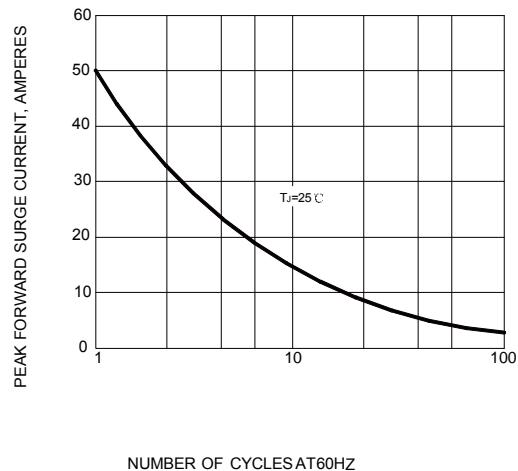
		RB151	RB152	RB153	RB154	RB155	RB156	RB157	UNITS
Maximum recurrent peak reverse voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS voltage	$V_{RMS}$	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum average forward Output current @ $T_A=55^\circ C$	$I_{F(AV)}$	1.5						A	
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load	$I_{FSM}$	50.0						A	
Maximum instantaneous forward voltage @ 1.5 A	$V_F$	1.0						V	
Maximum reverse current @ $T_A=25^\circ C$ at rated DC blocking voltage @ $T_A=100^\circ C$	$I_R$	10.0 0.5						$\mu A$ mA	
Operating junction temperature range	$T_J$	-55 ---- +125						°C	
Storage temperature range	$T_{STG}$	-55 ---- +150						°C	

## RATINGS AND CHARACTERISTIC CURVES

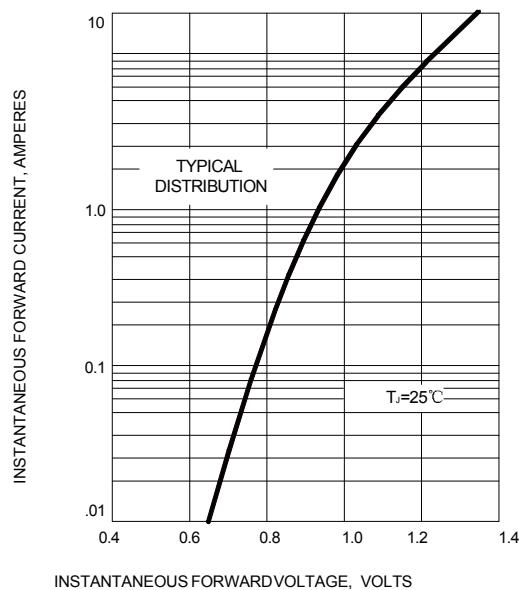
**FIG.1 – DERATING CUTPUT RECTIFIED CURRENT**



**FIG.2 – MAXIMUM FORWARD SURGE CURRENT**



**FIG.3 – TYPICAL FORWARD CHARACTERISTIC**



**FIG.4 – TYPICAL REVERSE CHARACTERISTIC**

